

# DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

## **HEF40106B**

### **gates**

### **Hex inverting Schmitt trigger**

Product specification  
File under Integrated Circuits, IC04

January 1995

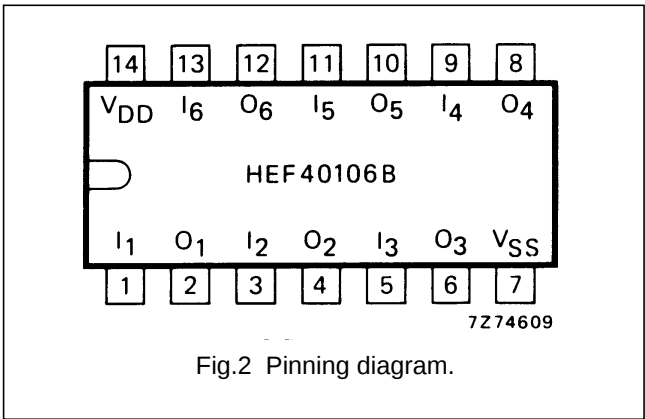
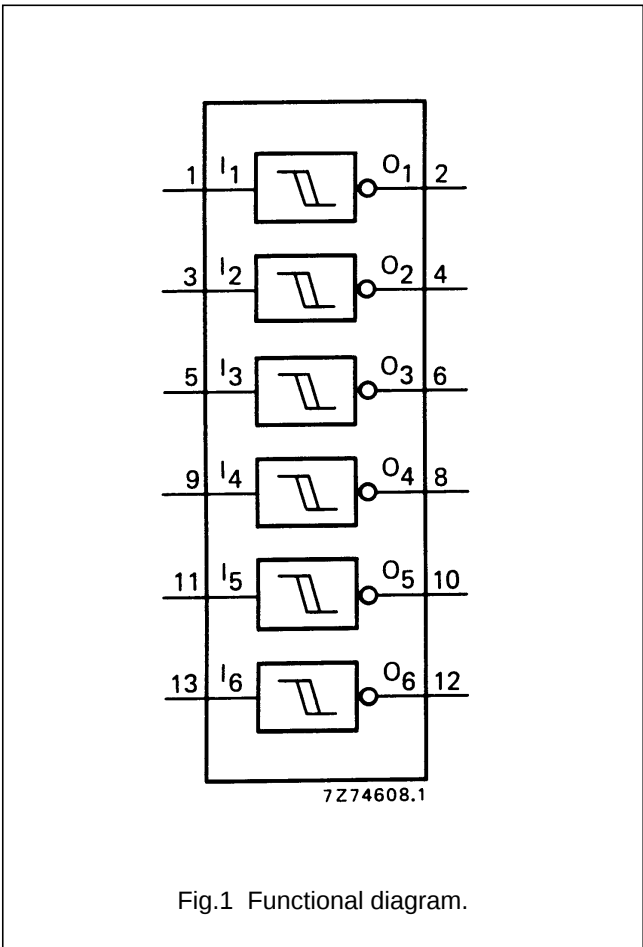
Hex inverting Schmitt trigger

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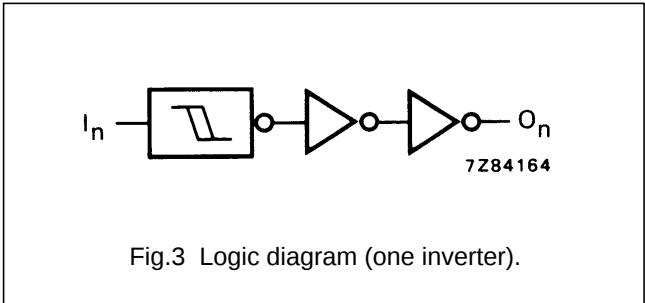
DESCRIPTION

Each circuit of the HEF40106B functions as an inverter with Schmitt-trigger action. The Schmitt-trigger switches at different points for the positive and negative-going input signals. The difference between the positive-going voltage ( $V_P$ ) and the negative-going voltage ( $V_N$ ) is defined as hysteresis voltage ( $V_H$ ).

This device may be used for enhanced noise immunity or to “square up” slowly changing waveforms.



- HEF40106BP(N): 14-lead DIL; plastic (SOT27-1)
- HEF40106BD(F): 14-lead DIL; ceramic (cerdip) (SOT73)
- HEF40106BT(D): 14-lead SO; plastic (SOT108-1)
- ( ): Package Designator North America



FAMILY DATA,  $I_{DD}$  LIMITS category GATES

See Family Specifications

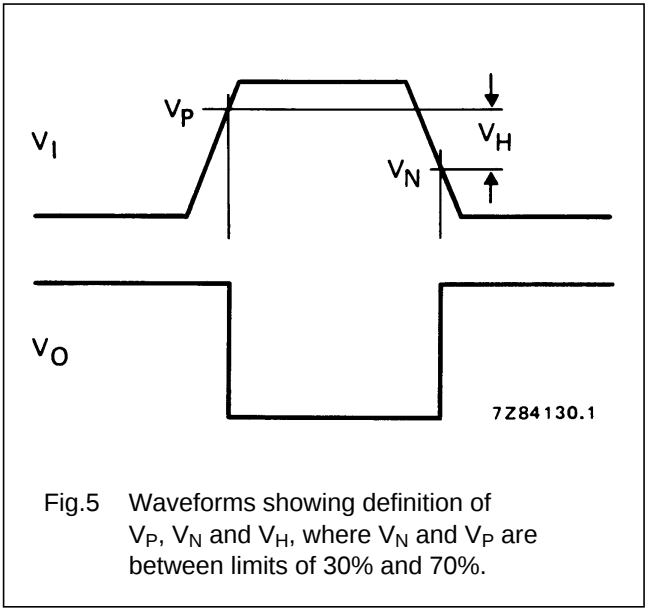
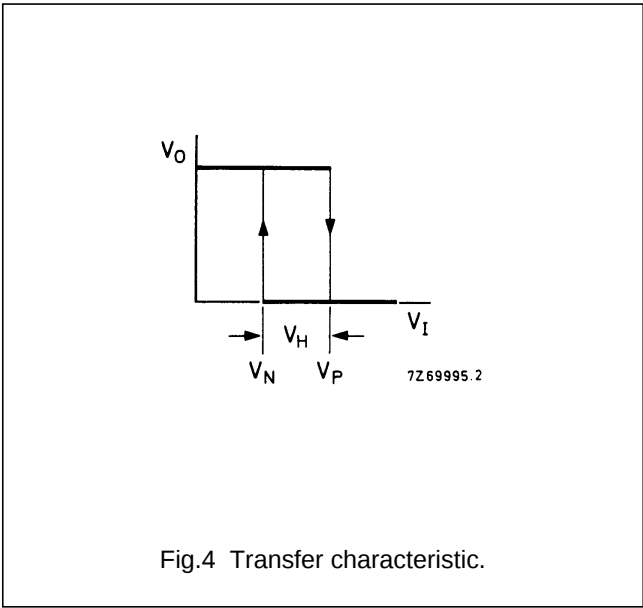
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DC CHARACTERISTICS

$V_{SS} = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$

|                                                     | $V_{DD}$<br>V | SYMBOL | MIN. | TYP. | MAX. |   |
|-----------------------------------------------------|---------------|--------|------|------|------|---|
| Hysteresis<br>voltage                               | 5             | $V_H$  | 0,5  | 0,8  |      | V |
|                                                     | 10            |        | 0,7  | 1,3  |      | V |
|                                                     | 15            |        | 0,9  | 1,8  |      | V |
| Switching levels<br>positive-going<br>input voltage | 5             | $V_P$  | 2    | 3,0  | 3,5  | V |
|                                                     | 10            |        | 3,7  | 5,8  | 7    | V |
|                                                     | 15            |        | 4,9  | 8,3  | 11   | V |
| negative-going<br>input voltage                     | 5             | $V_N$  | 1,5  | 2,2  | 3    | V |
|                                                     | 10            |        | 3    | 4,5  | 6,3  | V |
|                                                     | 15            |        | 4    | 6,5  | 10,1 | V |



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## AC CHARACTERISTICS

$V_{SS} = 0$  V;  $T_{amb} = 25$  °C;  $C_L = 50$  pF; input transition times  $\leq 20$  ns

|                                                            | $V_{DD}$<br>V | SYMBOL    | TYP.           | MAX.            |    | TYPICAL EXTRAPOLATION<br>FORMULA                                                       |
|------------------------------------------------------------|---------------|-----------|----------------|-----------------|----|----------------------------------------------------------------------------------------|
| Propagation delays<br>$I_n \rightarrow O_n$<br>HIGH to LOW | 5<br>10<br>15 | $t_{PHL}$ | 90<br>35<br>30 | 180<br>70<br>60 | ns | 63 ns + (0,55 ns/pF) $C_L$<br>24 ns + (0,23 ns/pF)<br>22 ns + (0,16 ns/pF) $C_L$       |
| LOW to HIGH                                                | 5<br>10<br>15 | $t_{PLH}$ | 75<br>35<br>30 | 150<br>70<br>60 | ns | 48 ns + (0,55 ns/pF) $C_L$<br>24 ns + (0,23 ns/pF) $C_L$<br>22 ns + (0,16 ns/pF) $C_L$ |
| Output transition times<br>HIGH to LOW                     | 5<br>10<br>15 | $t_{THL}$ | 60<br>30<br>20 | 120<br>60<br>40 | ns | 10 ns + (1,0 ns/pF) $C_L$<br>9 ns + (0,42 ns/pF) $C_L$<br>6 ns + (0,28 ns/pF) $C_L$    |
| LOW to HIGH                                                | 5<br>10<br>15 | $t_{TLH}$ | 60<br>30<br>20 | 120<br>60<br>40 | ns | 10 ns + (1,0 ns/pF) $C_L$<br>9 ns + (0,42 ns/pF) $C_L$<br>6 ns + (0,28 ns/pF) $C_L$    |

|                                                 | $V_{DD}$<br>V | TYPICAL FORMULA FOR P ( $\mu$ W)                                                                                                                 |                                                                                                                                                                         |
|-------------------------------------------------|---------------|--------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Dynamic power<br>dissipation per<br>package (P) | 5<br>10<br>15 | $2\,300 f_i + \sum (f_o C_L) \times V_{DD}^2$<br>$9\,000 f_i + \sum (f_o C_L) \times V_{DD}^2$<br>$20\,000 f_i + \sum (f_o C_L) \times V_{DD}^2$ | where<br>$f_i$ = input freq. (MHz)<br>$f_o$ = output freq. (MHz)<br>$C_L$ = load capacitance (pF)<br>$\sum (f_o C_L)$ = sum of outputs<br>$V_{DD}$ = supply voltage (V) |

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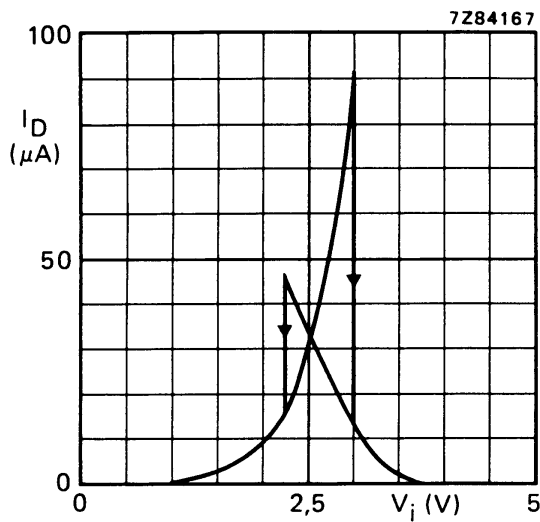


Fig.6 Typical drain current as a function of input voltage;  $V_{DD} = 5\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

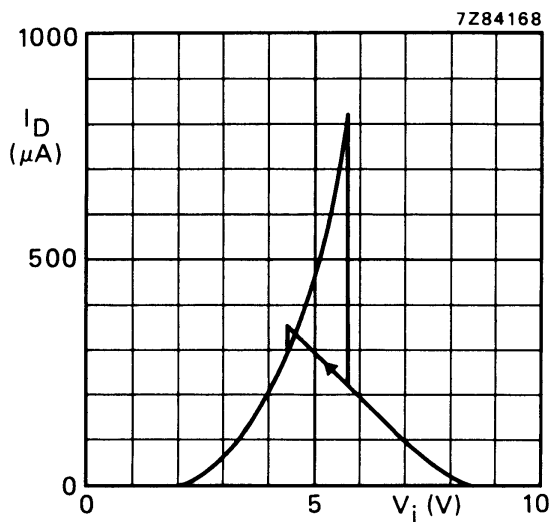


Fig.7 Typical drain current as a function of input voltage;  $V_{DD} = 10\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

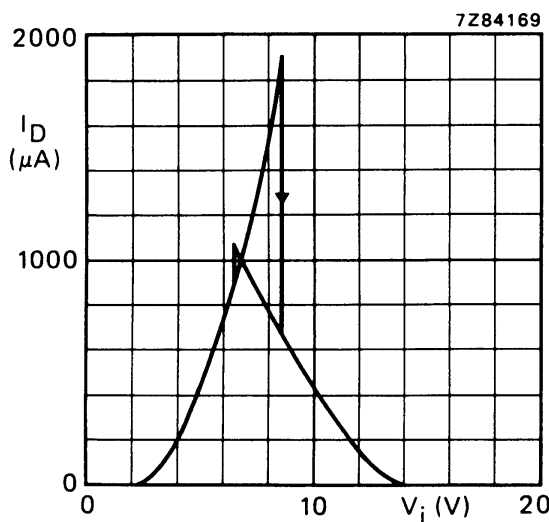
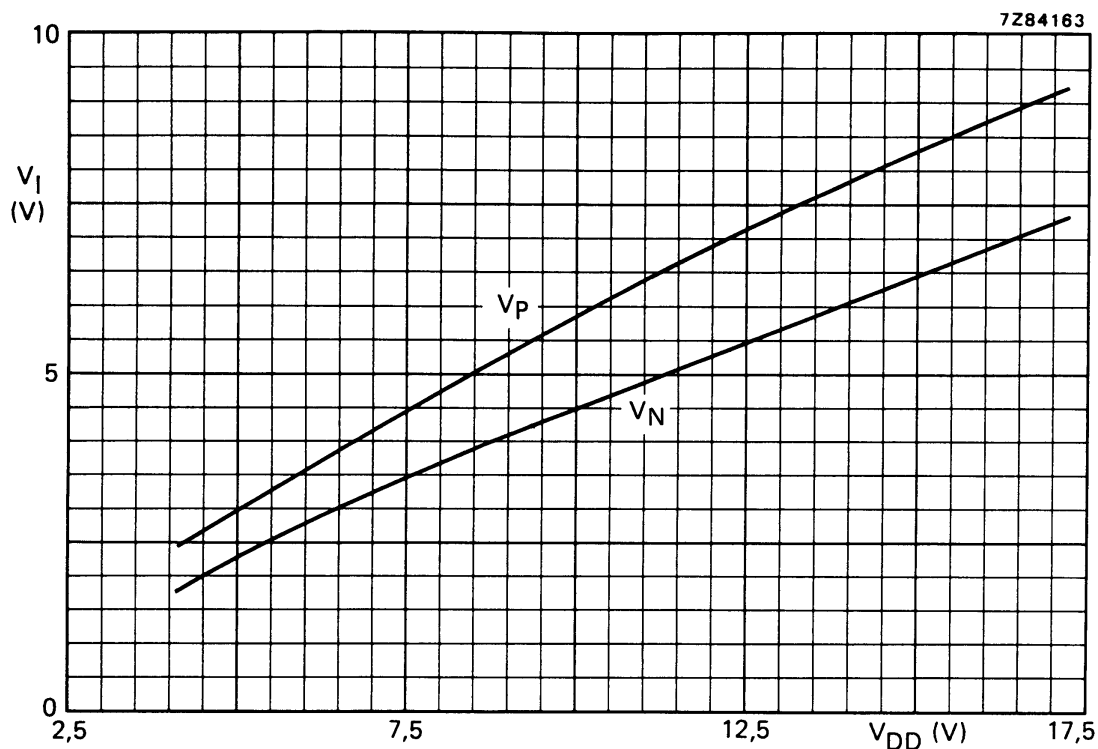
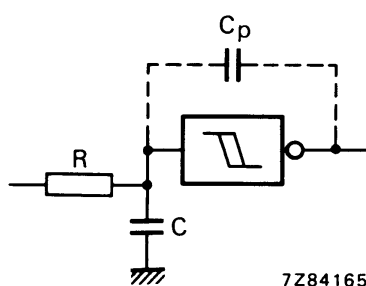


Fig.8 Typical drain current as a function of input voltage;  $V_{DD} = 15\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

## Hex inverting Schmitt trigger

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If a Schmitt trigger is driven via a high impedance ( $R > 1\text{ k}\Omega$ ) then it is necessary to incorporate a capacitor  $C$  of such value that:  $\frac{C}{C_p} > \frac{V_{DD} - V_{SS}}{V_H}$ , otherwise oscillation can occur on the edges of a pulse.

$C_p$  is the external parasitic capacitance between input and output; the value depends on the circuit board layout.

## Hex inverting Schmitt trigger

## HEF40106B gates

### APPLICATION INFORMATION

Some examples of applications for the HEF40106B are:

- Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators.

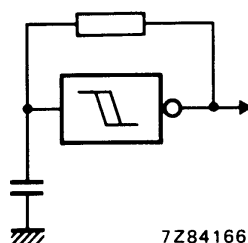


Fig.11 The HEF40106B used as an astable multivibrator.